

DATASHEET

4 PIN SOP PHOTOTRANSISTOR PHOTOCOUPLER EL357N-G Series



Features:

- Halogens free (Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm)
- Current transfer ratio (CTR: 50~600% at I_F =5mA, V_{CE} =5V)
- High isolation voltage between input and output (Viso=3750 V rms)
- Compact 4 Pin SOP with a 2.0mm profile
- Compliance with EU REACH
- Pb free and RoHS compliant
- UL and cUL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

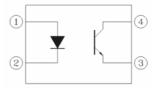
Description

The EL357N-G series contains an infrared emitting diode, optically coupled to a phototransistor detector. The devices in a 4-pin small outline SMD package.

Applications

- DC-DC Converters
- Programmable controllers
- Telecommunication equipments
- Signal transmission between circuits of different potentials and impedances

<u>Schematic</u>



Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector



Absolute Maximum Ratings (Ta=25℃)

Parameter	Symbol	Rating	Unit
Forward current	l _F	50	mA
Peak forward current (1us, pulse)	I _{FP}	1	А
Reverse voltage	V _R	6	V
Power dissipation	Б	70	mW
Derating factor (about Ta=100°C)	PD	2.9	mW/C
Power dissipation	P _C -	150	mW
Derating factor (above $T_a = 70^{\circ}C$)		3.7	mW/°C
Collector current	I _C	50	mA
Collector-Emitter voltage	V _{CEO}	80	V
Emitter-Collector voltage	V _{ECO}	7	V
Total Power Dissipation		200	mW
Isolation Voltage*1		3750	V rms
Operating temperature		-55 ~ +110	°C
Storage temperature		-55 ~ +125	°C
Temperature*2	T _{SOL}	260	°C
	Forward current Peak forward current (1us, pulse) Reverse voltage Power dissipation Derating factor (about Ta=100°C) Power dissipation Derating factor (above Ta = 70°C) Collector current Collector-Emitter voltage Emitter-Collector voltage er Dissipation /oltage*1 temperature	Forward current Peak forward current (1us, pulse) Reverse voltage VR Power dissipation Derating factor (about Ta=100°C) Power dissipation Derating factor (above Ta = 70°C) Collector current Ic Collector-Emitter voltage VECO Emitter-Collector voltage VECO Prot Voltage*1 VISO temperature Topr Totage	Forward current I_F 50 Peak forward current (1us, pulse) I_{FP} 1 Reverse voltage V_R 6 Power dissipation Derating factor (about Ta=100°C) P_D $\frac{70}{2.9}$ Power dissipation Derating factor (above $T_a = 70^{\circ}C$) P_C $\frac{150}{3.7}$ Collector current I_C 50 Collector-Emitter voltage V_{CEO} 80 Emitter-Collector voltage V_{CEO} 7 or Dissipation P_{TOT} 200 voltage*1 V_{ISO} 3750 temperature T_{OPR} -55 ~ +110 emperature T_{STG} -55 ~ +125

Notes:

^{*1} AC for 1 minute, R.H.= $40 \sim 60\%$ R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.

^{*2} For 10 seconds



Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage	V _F	-	1.2	1.4	V	$I_F = 20 \text{mA}$
Reverse current	I_R	-	-	10	μΑ	$V_R = 4V$
Input capacitance	C _{in}	-	30	250	pF	V = 0, f = 1kHz

Note: Reverse Voltage(VR) Condition is applied to IR test only The device is not designed for reverse operation

Output

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Emitter dark current	I _{CEO}	-	-	100	nA	V _{CE} = 20V, I _F = 0mA
Collector-Emitter breakdown voltage	BV _{CEO}	80	-	-	V	$I_C = 0.1 \text{mA}$
Emitter-Collector breakdown voltage	BV _{ECO}	7	-	-	V	$I_{E} = 0.01 \text{mA}$

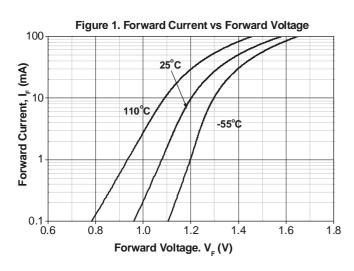
Transfer Characteristics (T_a=25°C unless specified otherwise)

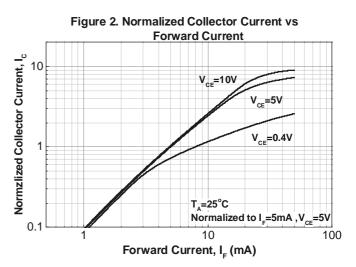
Pa	rameter	Symbol	Min	Тур.	Max.	Unit	Condition	
Current Transfer ratio EL357NB EL357NB EL357NC EL357NC EL357ND EL357ND EL357NF	EL357N		50	- 1	600			
	EL357NA		80	-	160			
	EL357NB		130		260		$I_F = 5 \text{mA}$, $V_{CE} = 5 \text{V}$	
	EL357NC	CTR	200	-	400			
	EL357ND	- - -	300	-	600			
	EL357NE		100	-	200			
	EL357NF		150	-	300			
Collector-lesaturation		V _{CE(sat)}	-	0.1	0.2	V	$I_F = 20\text{mA}$, $I_C = 1\text{mA}$	
Isolation re	esistance	R _{IO}	5×10 ¹⁰	-	-	Ω	V _{IO} = 500Vdc, 40~60% R.H.	
Floating ca	apacitance	C_{IO}	-	0.6	1.0	pF	$V_{IO} = 0$, $f = 1MHz$	
Rise time		t _r	-	3	18		$V_{CE} = 2V$, $I_C = 2mA$,	
Fall time	Fall time		-	4	18	μs	$R_L = 100\Omega$	

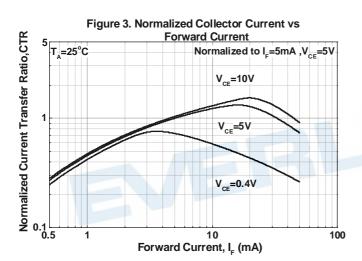
^{*} Typical values at T_a = 25°C

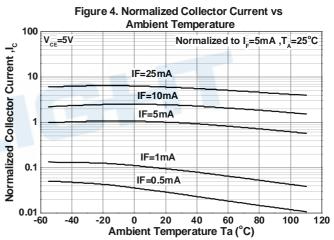


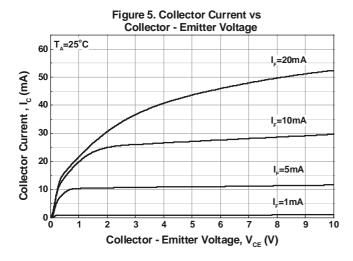
Typical Electro-Optical Characteristics Curves

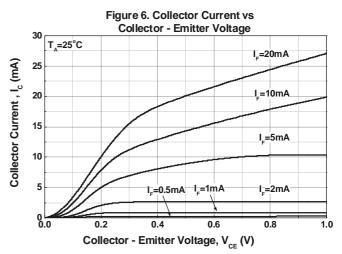




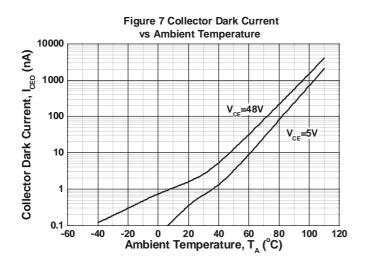


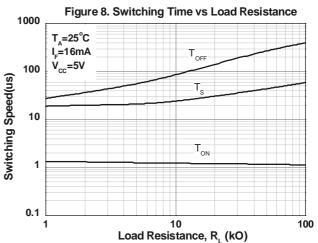


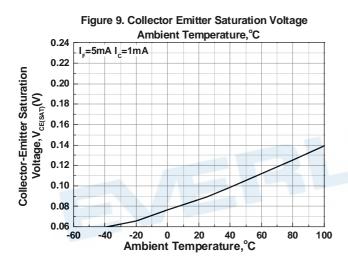








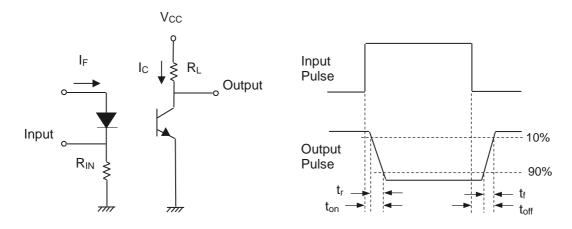




Note: The graphs shown in this datasheet are representing typical data only and do not show guaranteed values



Figure 10. Switching Time Test Circuit & Waveforms



Order Information

Part Number

EL357N(X)(Y)-VG

Note

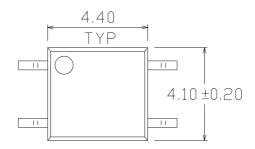
X = CTR Rank (A, B, C, D, E, F or none) Y = Tape and reel option (TA, TB or none).

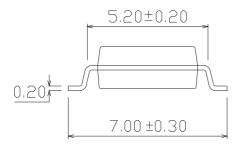
V = VDE (option) G = Halogen free

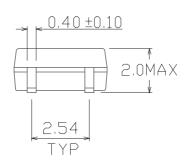
Option	Description	Packing quantity
None	Standard SMD option	100 units per tube
-V	Standard SMD option + VDE	100 units per tube
(TA)	TA Tape & reel option	3500 units per reel
(TB)	TB Tape & reel option	3500 units per reel
(TA)-V	TA Tape & reel option + VDE	3500 units per reel
(TB)-V	TB Tape & reel option + VDE	3500 units per reel



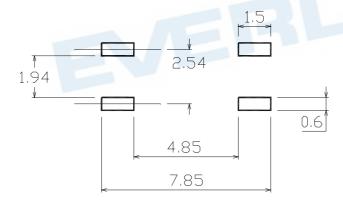
Package Dimension (Dimensions in mm)







Recommended pad layout for surface mount leadform





Device Marking



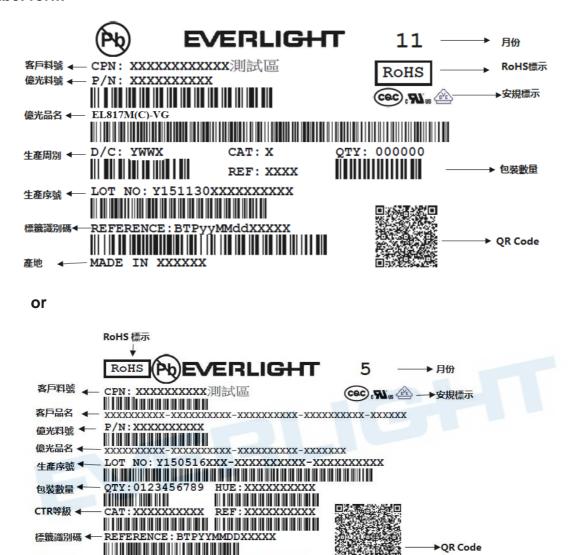
Notes

EL denotes Everlight
357N denotes Device Number
R denotes CTR Rank
Y denotes 1 digit Year code
WW denotes 2 digit Week code
V denotes VDE approved (optional)



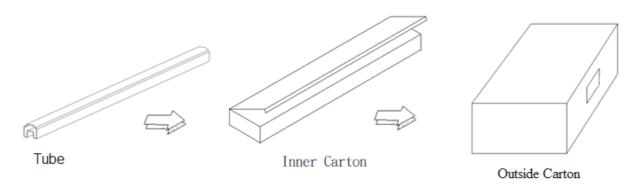


Label form



TUBE Dimension

MSL等級 ◆ MSL-XX

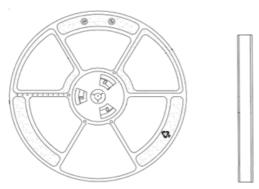


MADE IN XXXXXX

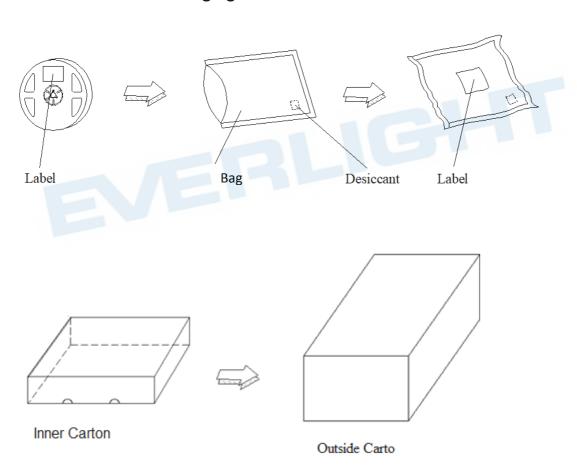
產地



Reel Dimension

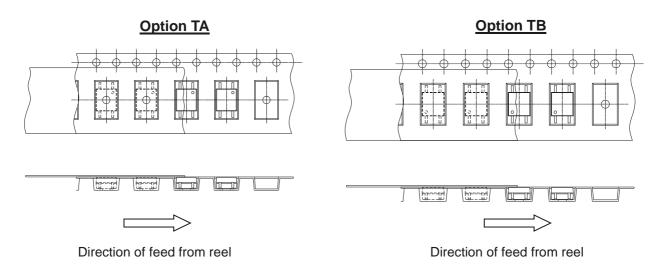


Moisture Resistant Packaging

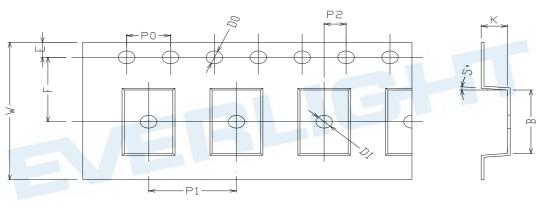


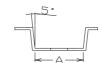


Tape & Reel Packing Specifications



Tape dimensions





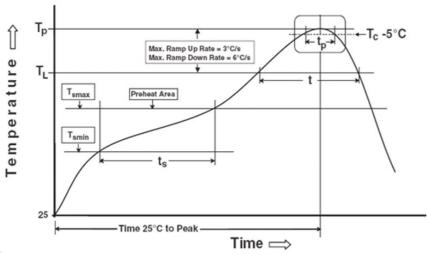
Dimension No.	Α	В	Do	D1	E	F
Dimension (mm)	4.4 ± 0.1	7.4 ± 0.1	1.5 + 0.1/-0	1.5 ± 0.1	1.75± 0.1	7.5 ± 0.05
Dimension No.	Ро	P1	P2	t	W	К
Dimension (mm)	4.0 ± 0.15	8.0 ± 0.1	2.0 ± 0.1	0.25 ± 0.03	16.0 ± 0.2	2.4± 0.1



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Preheat

Temperature min (T_{smin})

Temperature max (T_{smax}) Time $(T_{smin}$ to $T_{smax})$ (t_s)

Average ramp-up rate (T_{smax} to T_p)

Other

Liquidus Temperature (T_L)

Time above Liquidus Temperature (t L)

Peak Temperature (T_P)

Time within 5 °C of Actual Peak Temperature: TP - 5°C

Ramp- Down Rate from Peak Temperature

Time 25°C to peak temperature

Reflow times

Reference: IPC/JEDEC J-STD-020D

150 °C 200°C

60-120 seconds

3 °C/second max

217 °C

60-100 sec

260°C

30 s

6°C /second max.

8 minutes max.

3 times



Precautions for General Storage

- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5°C to 35°C and 20 % to 60 %,respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- When restoring devices after removal from their packing, use anti-static containers.
- Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.



DATASHEET 4 PIN SOP PHOTOTRANSISTOR PHOTOCOUPLER EL357N-G series



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